

# FDME905PT

## P-Channel PowerTrench® MOSFET

-12 V, -8 A, 22 mΩ

### Features

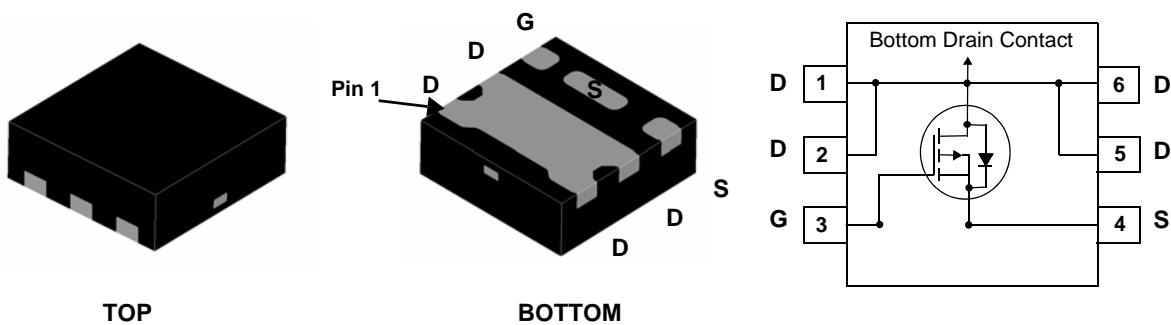
- Max  $r_{DS(on)}$  = 22 mΩ at  $V_{GS} = -4.5$  V,  $I_D = -8$  A
- Max  $r_{DS(on)}$  = 26 mΩ at  $V_{GS} = -2.5$  V,  $I_D = -7.3$  A
- Max  $r_{DS(on)}$  = 97 mΩ at  $V_{GS} = -1.8$  V,  $I_D = -3.8$  A
- Low profile: 0.55 mm maximum in the new package MicroFET 1.6x1.6 Thin
- Free from halogenated compounds and antimony oxides
- RoHS Compliant



### General Description

This device is designed specifically for battery charging or load switching in cellular handset and other ultraportable applications. It features a MOSFET with low on-state resistance.

The MicroFET 1.6x1.6 Thin package offers exceptional thermal performance for its physical size and is well suited to switching and linear mode applications.



MicroFET 1.6x1.6 Thin

### MOSFET Maximum Ratings $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Rated Value	Units
$V_{DS}$	Drain to Source Voltage	-12	V
$V_{GS}$	Gate to Source Voltage	±8	V
$I_D$	Drain Current -Continuous	-8	A
	-Pulsed	-30	
$P_D$	Power Dissipation	2.1	W
	Power Dissipation	0.7	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	°C

### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	4.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	60	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1b)	175	

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
E95	FDME905PT	MicroFET 1.6x1.6 Thin	7"	8 mm	5000 units

## Electrical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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### Off Characteristics

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = -250\text{ }\mu\text{A}, V_{GS} = 0\text{ V}$	-12			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250\text{ }\mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		-8.7		mV/ $^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = -9.6\text{ V}, V_{GS} = 0\text{ V}$			-1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 8\text{ V}, V_{DS} = 0\text{ V}$			$\pm 100$	nA

### On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250\text{ }\mu\text{A}$	-0.4	-0.7	-1.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250\text{ }\mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		2.5		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = -4.5\text{ V}, I_D = -8\text{ A}$		18	22	m $\Omega$
		$V_{GS} = -2.5\text{ V}, I_D = -7.3\text{ A}$		22	26	
		$V_{GS} = -1.8\text{ V}, I_D = -3.8\text{ A}$		28	97	
		$V_{GS} = -4.5\text{ V}, I_D = -8\text{ A}, T_J = 125\text{ }^\circ\text{C}$		23	32	
$g_{FS}$	Forward Transconductance	$V_{DS} = -5\text{ V}, I_D = -8\text{ A}$		38		S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = -6\text{ V}, V_{GS} = 0\text{ V},$ $f = 1\text{ MHz}$		1740	2315	pF
$C_{oss}$	Output Capacitance			350	525	pF
$C_{rss}$	Reverse Transfer Capacitance			311	465	pF

### Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = -6\text{ V}, I_D = -8\text{ A},$ $V_{GS} = -4.5\text{ V}, R_{GEN} = 6\text{ }\Omega$		9.5	19	ns
$t_r$	Rise Time			8	16	ns
$t_{d(off)}$	Turn-Off Delay Time			90	144	ns
$t_f$	Fall Time			42	67	ns
$Q_g$	Total Gate Charge			14	20	nC
$Q_{gs}$	Gate to Source Gate Charge	$V_{DD} = -6\text{ V}, I_D = -8\text{ A},$ $V_{GS} = -4.5\text{ V}$		2.4		nC
$Q_{gd}$	Gate to Drain "Miller" Charge			3		nC

### Drain-Source Diode Characteristics

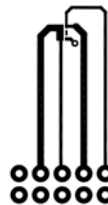
$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{GS} = 0\text{ V}, I_S = -8\text{ A}$ (Note 2)		-0.8	-1.2	V
		$V_{GS} = 0\text{ V}, I_S = -1.8\text{ A}$ (Note 2)		-0.7	-1.2	
$t_{rr}$	Reverse Recovery Time	$I_F = -8\text{ A}, di/dt = 100\text{ A}/\mu\text{s}$		17	31	ns
$Q_{rr}$	Reverse Recovery Charge			4.5	10	nC

#### Notes:

1.  $R_{\theta JA}$  is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



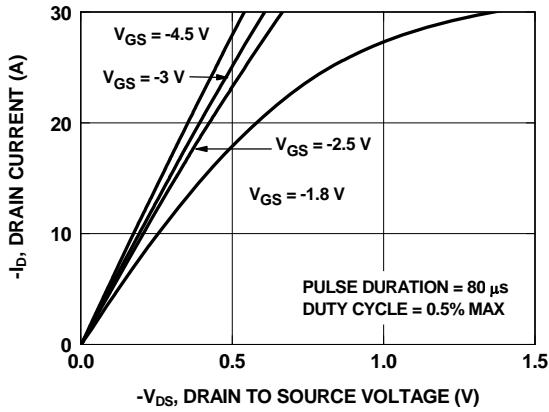
a. 60  $^\circ\text{C}/\text{W}$  when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



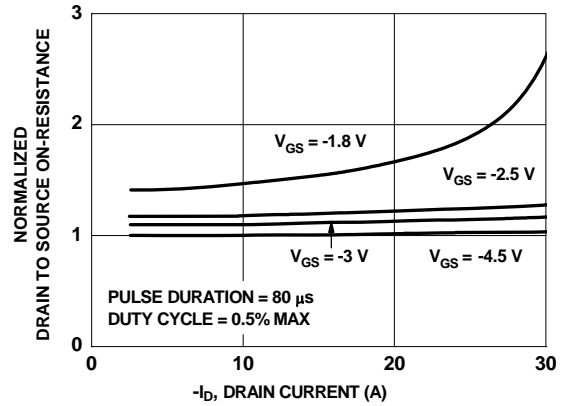
b. 175  $^\circ\text{C}/\text{W}$  when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty cycle < 2.0 %.

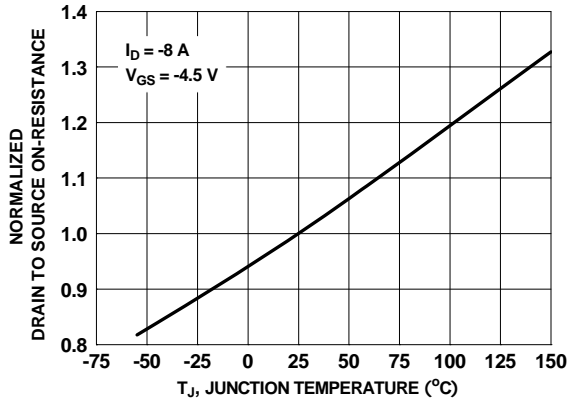
**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted



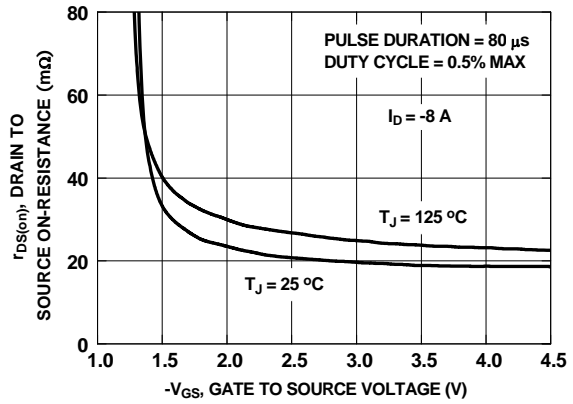
**Figure 1. On-Region Characteristics**



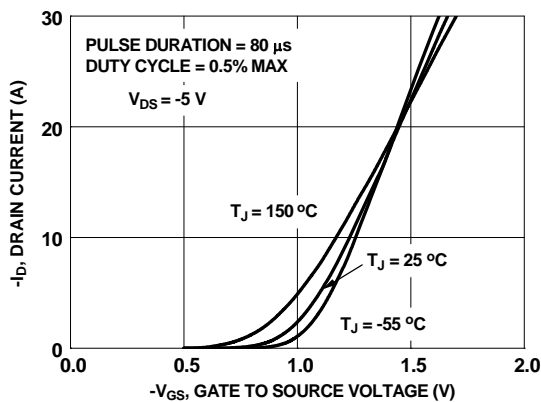
**Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage**



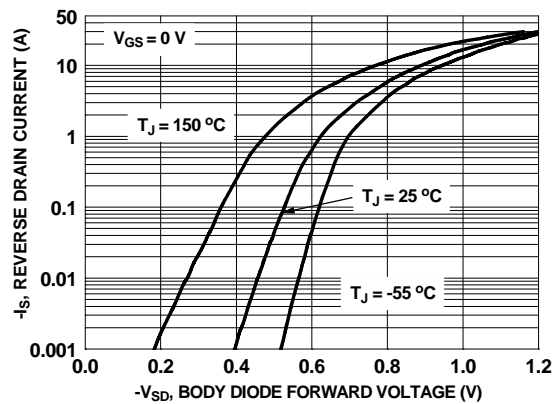
**Figure 3. Normalized On-Resistance vs Junction Temperature**



**Figure 4. On-Resistance vs Gate to Source Voltage**

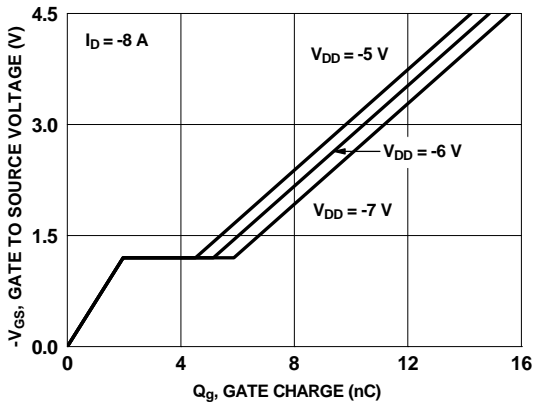


**Figure 5. Transfer Characteristics**

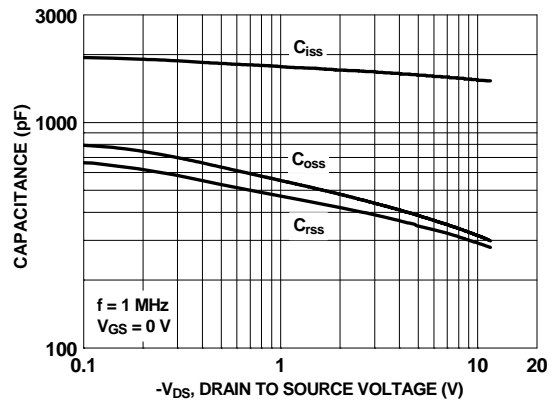


**Figure 6. Source to Drain Diode Forward Voltage vs Source Current**

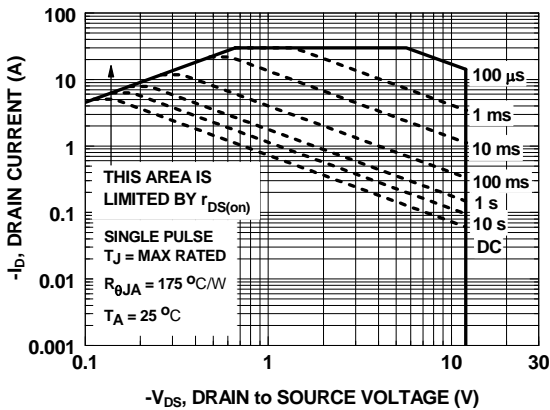
**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted



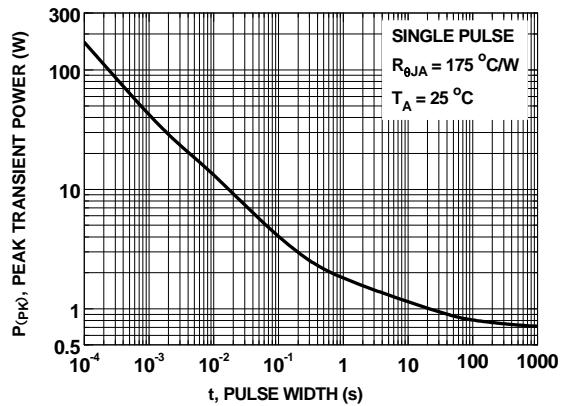
**Figure 7. Gate Charge Characteristics**



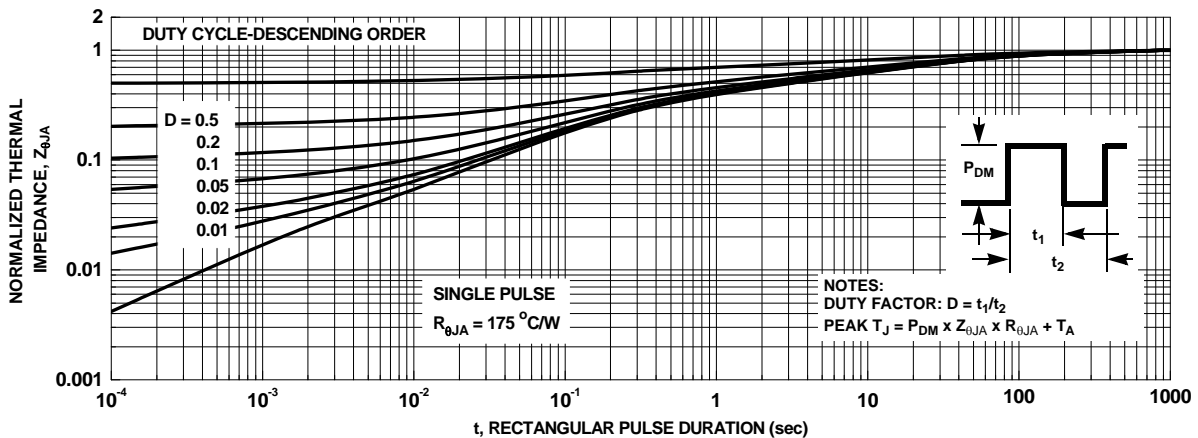
**Figure 8. Capacitance vs Drain to Source Voltage**



**Figure 9. Forward Bias Safe Operating Area**

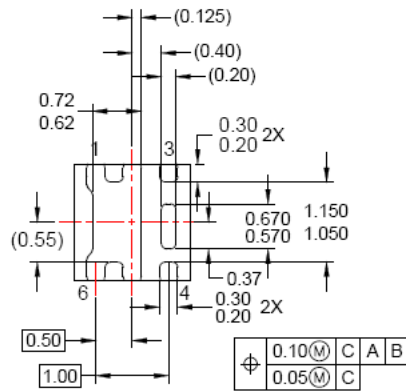
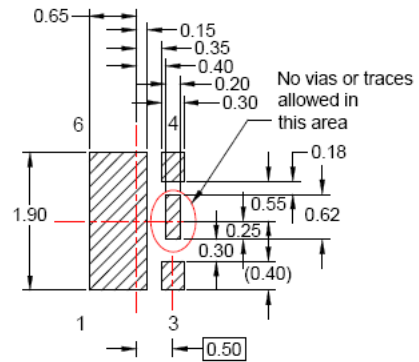
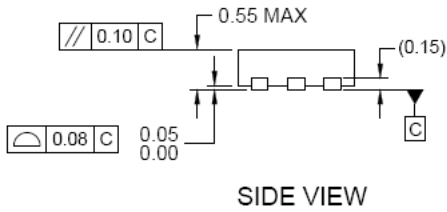
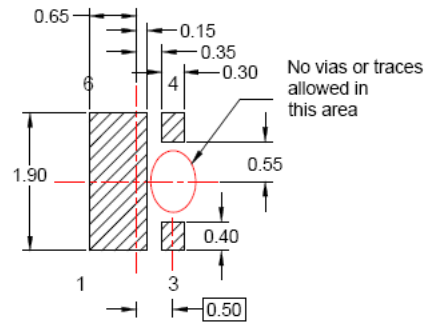
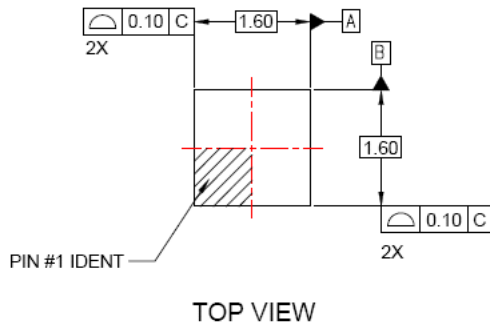


**Figure 10. Single Pulse Maximum Power Dissipation**



**Figure 11. Junction-to-Ambient Transient Thermal Response Curve**

## Dimensional Outline and Pad Layout





- NOTES:
- A. DOES NOT FULLY CONFORM TO JEDEC REGISTRATION
  - B. DIMENSIONS ARE IN MILLIMETERS.
  - C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
  - D. LAND PATTERN RECOMMENDATION IS BASED ON FSC DESIGN ONLY



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| AX-CAP®*                                                                          | FRFET®                                          | PowerXS™                              | <b>SYSTEM GENERAL</b> ®*                                                            |
| BitSiC™                                                                           | Global Power Resource <sup>SM</sup>             | Programmable Active Droop™            | TinyBoost®                                                                          |
| Build it Now™                                                                     | GreenBridge™                                    | QFET®                                 | TinyBuck®                                                                           |
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| CorePOWER™                                                                        | Green FPS™ e-Series™                            | Quiet Series™                         | TinyLogic®                                                                          |
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| Fairchild®                                                                        | MicroPak2™                                      | SuperFET®                             | UHC®                                                                                |
| Fairchild Semiconductor®                                                          | MillerDrive™                                    | SuperSOT™-3                           | Ultra FRFET™                                                                        |
| FACT Quiet Series™                                                                | MotionMax™                                      | SuperSOT™-6                           | UniFET™                                                                             |
| FACT®                                                                             | mWSave®                                         | SuperSOT™-8                           | VCX™                                                                                |
| FAST®                                                                             | OptoHiT™                                        | SupreMOS®                             | VisualMax™                                                                          |
| FastvCore™                                                                        | OPTOLOGIC®                                      | SyncFET™                              | VoltagePlus™                                                                        |
| FETBench™                                                                         | OPTOPLANAR®                                     |                                       | XS™                                                                                 |
| FPS™                                                                              |                                                 |                                       |                                                                                     |

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